

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	2	(silicon same (micro near cavity)) same (ion near implant\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/09/28 06:55
L2	27	moriceau-hubert.in.	US-PGPUB; USPAT	OR	OFF	2005/09/28 06:56
L3	3	2 and inclusion	US-PGPUB; USPAT	OR	OFF	2005/09/28 07:00
L4	3846	(wafer same (cleav\$3 or dic\$3 or slic\$3 or split\$3 or fractur\$3)) same (anodiz\$3 or heat\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/09/28 07:02
L5	462	4 same (por\$3 or inclusion or micro near cavit\$3 or micro near bubble or cleavage near line or area)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/09/28 07:04
L6	120	5 and @pd<"19971230"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/09/28 07:12
L7	29435	(porous neare silicon) same (ion near implantat\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/09/28 08:00
L8	326	7 same (slic\$3 or cleav\$3 or dic\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/09/28 07:13
L9	218	8 and (heat\$3 or anodiz\$3 same silicon)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/09/28 07:13
L10	61	9 and @pd<"19971230"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/09/28 07:19
L11	435	438/458-460.ccls. and (micro near bubble or por\$3 or (gas near trap\$3))	US-PGPUB; USPAT	OR	OFF	2005/09/28 07:23
L12	42	11 and @pd<"19971230"	US-PGPUB; USPAT	OR	OFF	2005/09/28 07:23
L13	163156	(porous neare silicon) same etch\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/09/28 08:01

L14	10803	13 same (ion near implantat\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/09/28 08:01
L15	1550	(porous near silicon) same etch\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/09/28 08:01
L16	61	15 same (ion near implantat\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/09/28 08:02